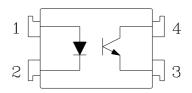


Description

The K1010 series consist of an infrared emitting diode, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Schematic



- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

Features

1. Current transfer ratio

(CTR : Min. 50% at I_F =5mA V_{CE} =5V)

2. High isolation voltage between input and output

(Viso: 5000Vrms)

- 3. Pb free and RoHS compliant
- 4. Agency Approvals
 - UL1577 / CUL C22.2 No.1 & NTC No.5, File No. E169586
 - VDE EN60747, File No.101347
 - FIMKO EN60065, File No. NCS/FI23149 A2
 - FIMKO EN60950, File No. NCS/FI24584 A1
 - SEMKO EN60065, File No. FI016484
 - SEMKO EN60950, File No. FI016433
 - CQC GB4943/GB8898-2011, File No.CQC10001049555 / CQC08001023986

Applications

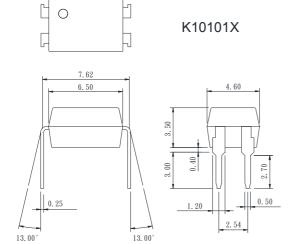
- System appliances
- Measuring instruments
- Computer terminals
- Programmable controllers
- · Medical instruments
- Physical and chemical equipment
- · Signal transmission between circuits of different potentials and impedances



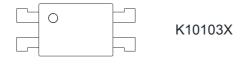
Outside Dimension

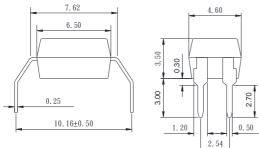
Unit: mm

1.Dual-in-line type.



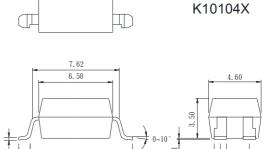
3.Long creepage distance type



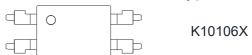


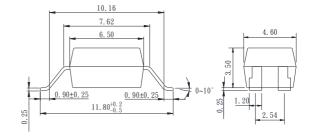
2. Surface mount type.

O D



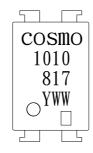
4.Long creepage distance for surface mount type.





TOLERANCE: ±0.2mm

Device Marking



Notes:

cosmo 1010 817 YWW Y: Year code / WW: Week code : CTR rank





Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	Peak forward current	I _{FM}	1	Α
	Reverse voltage	V _R	6	V
	Power dissipation	P _D	70	mW
Output	Collector-emitter voltage	V _{CEO}	80	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	Pc	150	mW
٦	Total power dissipation	P _{tot}	200	mW
I	solation voltage 1 minute	V _{iso}	5000	Vrms
Operating temperature		T _{opr}	-55 to +115	$^{\circ}\!\mathbb{C}$
Storage temperature		T _{stg}	-55 to +125	$^{\circ}\!\mathbb{C}$
Soldering temperature 10 seconds		T _{sol}	260	$^{\circ}\!\mathbb{C}$

• Electro-optical Characteristics

(Ta=25°ℂ)

	Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input	Forward voltage	V _F	I _F =20mA	-	1.2	1.4	V
	Peak forward voltage	V_{FM}	I _{FM} =0.5A	-	-	3.0	V
	Reverse current	I _R	V _R =4V	-	-	10	μ A
	Terminal capacitance	Ct	V=0, f=1KHz	-	30	-	pF
Output	Collector dark current	I _{CEO}	V _{CE} =20V, I _F =0	-	-	0.1	μ A
	Current transfer ratio	CTR	I _F =5mA, V _{CE} =5V	50	-	600	%
			I _F =1mA, V _{CE} =5V	15	-	-	/0
	Collector-emitter saturation	V _{CE(sat)}	I _F =20mA, I _C =1mA	-	0.1	0.2	V
Transfer	Isolation resistance	R _{iso}	DC500V	5x10 ¹⁰	10 ¹¹	-	Ω
charac- teristics	Floating capacitance	C _f	V=0, f=1MHz	-	0.6	1.0	pF
	Cut-off frequency	f _C	V_{CC} =5V, I_C =2mA, R_L =100 Ω	-	80	-	KHz
	Response time (Rise)	t _r	V_{CE} =2V, I_{C} =2mA, R_{L} =100 Ω	-	4	18	μ s
	Response time (Fall)	t _f		-	3	18	μ s



Classification table of current transfer ratio is shown below.

K1010 Model No.	CTR (%)
K1010 A	80 ~ 160
K1010 B	130 ~ 260
K1010 C	200 ~ 400
K1010 D	300 ~ 600
K1010 E	50 ~ 600

Fig.2 Collector Power Dissipation vs. Ambient Temperature

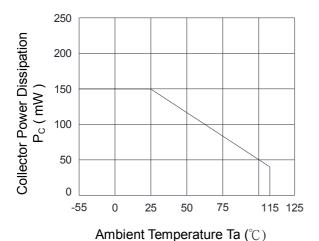


Fig.4 Forward Current vs. Ambient Temperature

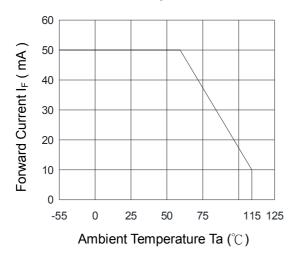


Fig.1 Current Transfer Ratio vs. Forward Current

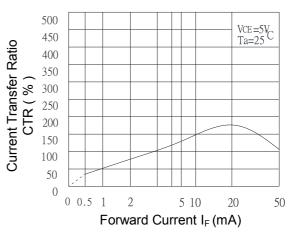
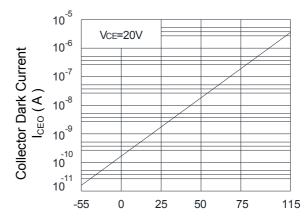


Fig.3 Collector Dark Current vs. Ambient Temperature



Ambient Temperature Ta (°C)

Fig.5 Forward Current vs. Forward Voltage

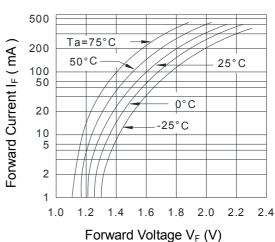






Fig.6 Collector Current vs. Collector-Emitter Voltage

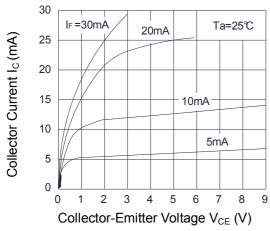


Fig.8 Collector-Emitter Saturation Voltage vs. Ambient Temperature

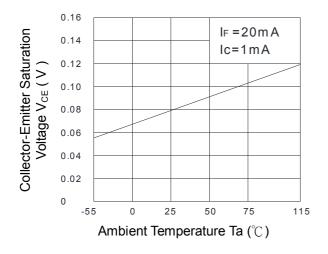


Fig.10 Response Time (Rise) vs. Load Resistance

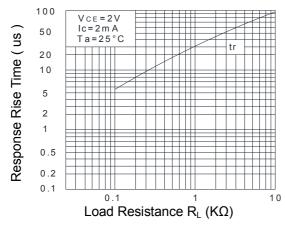


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

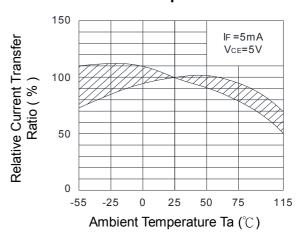
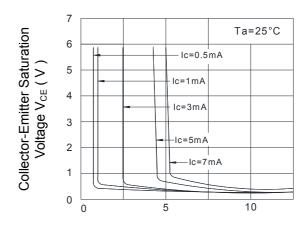
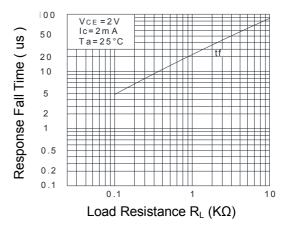


Fig.9 Collector-Emitter Saturation Voltage vs. Forward Current



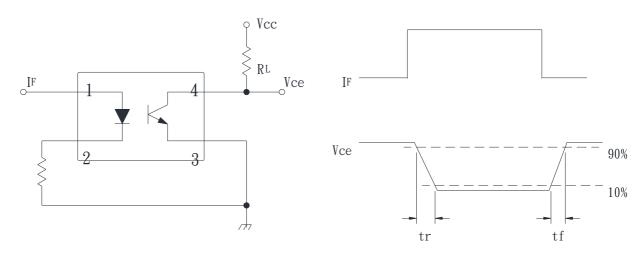
Forward Current I_F (mA)

Fig.11 Response Time (Fall) vs. Load Resistance





• Test Circuit for Response Time





Recommended Soldering Conditions

(a) Infrared reflow soldering:

■ Peak reflow soldering : 260°C or below (package surface temperature)

■ Time of peak reflow temperature : 10 sec
 ■ Time of temperature higher than 230°C : 30-60 sec
 ■ Time to preheat temperature from 180~190°C : 60-120 sec

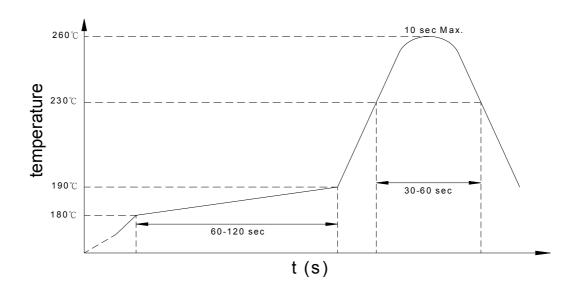
■ Time(s) of reflow: Two

■ Flux: Rosin flux containing small amount of chlorine (The

flux with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



(b) Wave soldering:

■ Temperature : 260°C or below (molten solder temperature)

■ Time : 10 seconds or less

■ Preheating conditions : 120°C or below (package surface temperature)

■ Time(s) of reflow : One

■ Flux : Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

(c) Cautions:

Fluxes: Avoid removing the residual flux with freon-based and chlorine-based

cleaning solvent.

Avoid shorting between portion of frame and leads.



Numbering System

K1010 X Y (Z)

Notes:

K1010 = Part No.

X = Lead form option (1,3,4,6)

 $Y = CTR \text{ rank option } (A \sim E)$

Z = Tape and reel option (TLD, TRU)

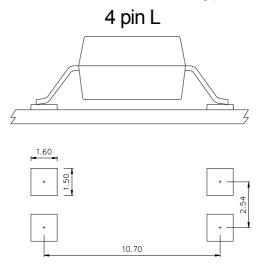
Option	Description	Packing quantity	
4 (TLD)	surface mount type package + TLD tape & reel option	2000 units per reel	
4 (TRU)	surface mount type package + TRU tape & reel option	2000 units per reel	
6 (TLD)	long creepage distance for surface mount type package + TLD tape & reel option	2000 units per reel	
6 (TRU)	long creepage distance for surface mount type package + TRU tape & reel option	2000 units per reel	

• Recommended Pad Layout for Surface Mount Lead Form

1. Surface mount type.

4 pin SMD

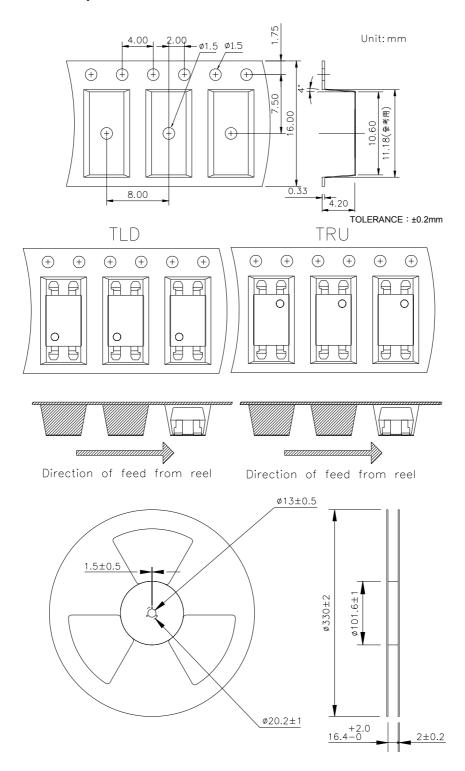
2.Long creepage distance for surface mount type.



Unit : mm

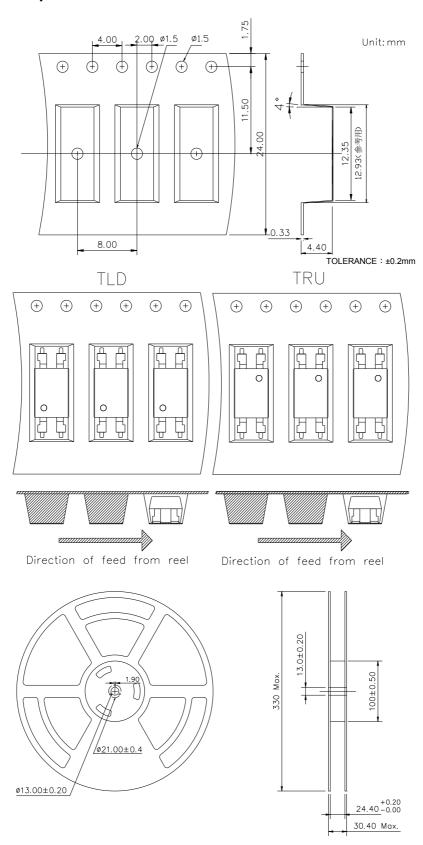


• 4-pin SMD Carrier Tape & Reel





• 4-pin L Carrier Tape & Reel



K1010 Series 4PIN PHOTOTRANSISTOR PHOTOCOUPLER



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- e. Electrical application
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- g. Consumer electronics
- h. Telecommunication

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- e. Equipment used for automotive vehicles, trains, ships...etc.

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